

UDN-6510A/R AND UDN-6514A/R HIGH-VOLTAGE SOURCE DRIVERS

FEATURES

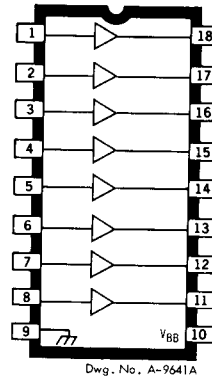
- TTL/MOS-Compatible Inputs
- High Output-Breakdown Voltage
- 40 mA Output-Current Capability
- Low Power Dissipation
- Reliable Monolithic Construction

EASY, EFFECTIVE INTERFACE for low-level TTL or MOS circuitry and high-voltage loads is available with Sprague UDN-6510A/R and UDN-6514A/R bipolar integrated circuits. These eight-channel devices drive the anodes of gas-discharge displays or the grids and anodes of large, multiplexed dot-matrix vacuum-fluorescent display panels.

Types UDN-6510A and UDN-6510R supply an output-voltage swing of up to 100 V with a maximum V_{BB} of 200 V. Typically, the output is switched between +100 V and +180 V.

Types UDN-6514A and UDN-6514R can switch output-voltage levels from ground to +135 V with appropriate pull-down circuitry and a maximum supply voltage of +140 V.

Each device in the series has eight independent drivers made up of switched constant-current level



shifters and PNP/NPN driver stages. Driver inputs operate with open-drain PMOS or CMOS, or with open-collector or standard TTL.

Types UDN-6510R and UDN-6514R are furnished in 18-pin dual in-line industrial-grade, hermetically sealed ceramic packages. Types UDN-6510A and UDN-6514A are supplied in inexpensive 18-pin dual in-line plastic packages. To simplify applications designs, all units have input connections on one side of the package and output pins on the other. All devices are rated for operation over the temperature range of -20°C to $+85^{\circ}\text{C}$.

ABSOLUTE MAXIMUM RATINGS

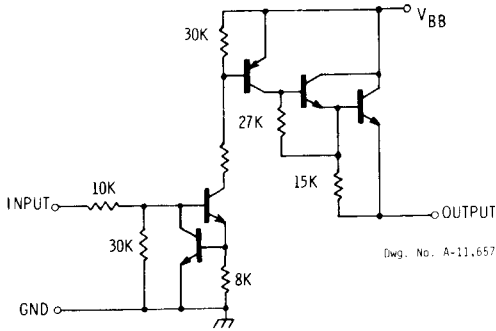
at $T_A = +25^{\circ}\text{C}$

($V_{REF} = \text{GROUND}$ unless otherwise specified)

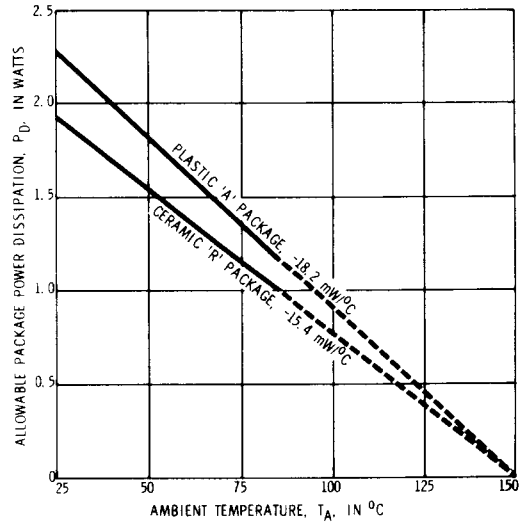
Supply Voltage, V_{BB} (UDN-6510A/R)	200 V
(UDN-6514A/R)	140 V
Output OFF Voltage ($V_{REF} = V_{BB}$), V_{OUT} (UDN-6510A/R)	-100 V
Input Voltage, V_{IN}	20 V
Output Current, I_{OUT}	-40 mA
Package Power Dissipation, P_D	See Graph
Operating Temperature Range, T_A	-20°C to $+85^{\circ}\text{C}$
Storage Temperature Range, T_S	-55°C to $+150^{\circ}\text{C}$

**UDN-6510A/R AND UDN-6514A/R
HIGH-VOLTAGE SOURCE DRIVERS**

**PARTIAL SCHEMATIC
One Driver (All Types)**



**PACKAGE POWER DISSIPATION
AS A FUNCTION OF TEMPERATURE**



Dwg. No. A-11.658

Caution: The high input impedance of these devices makes them susceptible to static discharge damage associated with handling and testing. Techniques similar to those used for handling MOS devices should be employed.

ELECTRICAL CHARACTERISTICS at $T_A = +25^\circ\text{C}$, $V_{BB} = 200\text{ V}$ (UDN-6510A/R) or 140 V (UDN-6514A/R), all voltage measurements are referenced to ground (unless otherwise noted)

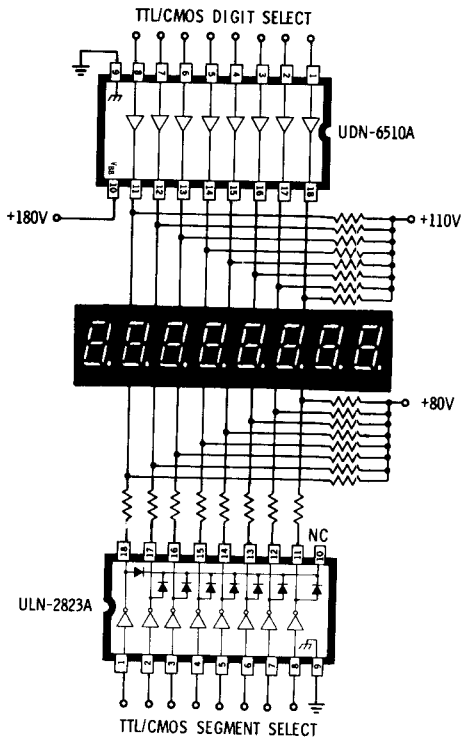
Characteristic	Symbol	Applicable Devices	Test Conditions	Limits			
				Min.	Typ.	Max.	Units
Output Leakage Current	I_{OUT}	UDN-6510A/R	$V_{OUT} = 100\text{ V}$, $V_{IN} = 0.4\text{ V}$, $T_A = +70^\circ\text{C}$	—	—	15	μA
		UDN-6514A/R	$V_{OUT} = 0\text{ V}$, $V_{IN} = 0.4\text{ V}$, $T_A = +70^\circ\text{C}$	—	—	15	μA
Output ON Voltage	V_{OUT}	UDN-6510A/R	$V_{IN} = 2.4\text{ V}$, $I_{OUT} = -25\text{ mA}$	195	197	—	V
		UDN-6514A/R	$V_{IN} = 2.4\text{ V}$, $I_{OUT} = -25\text{ mA}$	135	137	—	V
Input ON Current	I_{IN}	All	$V_{IN} = 2.4\text{ V}$	—	120	225	μA
			$V_{IN} = 5.0\text{ V}$	—	375	650	μA
Supply Current	I_{BB}	All	All inputs open	—	10	100	μA
			One input = 3.5 V	—	—	500	μA

RECOMMENDED OPERATING CONDITIONS

Supply Voltage	V_{BB}	UDN-6510A/R	55	—	180	V	
		UDN-6514A/R	55	—	130	V	
Output OFF Voltage	V_{OUT}	UDN-6510A/R	Reference V_{BB}	—	—	-80	V
Input ON Voltage	V_{IN}	All	2.4	—	15	V	
Output ON Current	I_{OUT}	All	—	—	-25	mA	

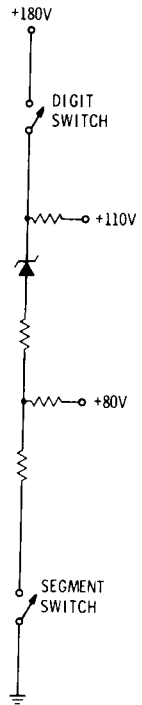
NOTE: Negative current is defined as coming out of the specified device pin.

TYPICAL PLASMA GAS-DISCHARGE DISPLAY APPLICATION



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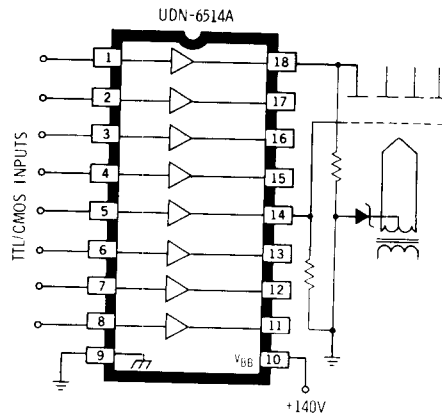
EQUIVALENT CIRCUIT



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MULTIPLEXED DOT-MATRIX VACUUM-FLUORESCENT DISPLAY APPLICATION



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